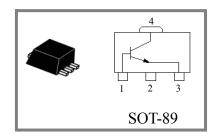


### NPNGeneral use transistor

1.2W 3A 30V

**Applications:** Can be used for switching and amplifying in various electrical and electronic equipments.



#### **MA RATING**

Parameters	Symbol	Rating	Unit			
Collector–emitter voltage (I <sub>B</sub> =0)	$V_{CEO}$	30	V			
Collector–base voltage (I <sub>E</sub> =0)	$V_{CBO}$	40	V			
Emitter – base voltage (I <sub>C</sub> =0)	$V_{\rm EBO}$	5	V			
Collector current	$I_{C}$	3	A			
Total power dissipation $(T_A=25^{\circ}C)^*$	P <sub>tot</sub>	1.2	W			
Max junction temperature	$T_{jm}$	150	$^{\circ}\!\mathbb{C}$			
Storage temperature	$T_{stg}$	-55~150	$^{\circ}\!\mathbb{C}$			
* mounted on printed circuit board.						

## 

		r	11 -				
Para	ameters	symbol	Test condition	min	typ	max	unit
Collector-emitter	r breakdown voltage	V <sub>(BR)CEO</sub>	$I_C=10$ mA, $I_B=0$	30			V
Collector-base base	reakdown voltage	V <sub>(BR)CBO</sub>	$I_C=1$ mA, $I_E=0$	40			V
Emitter– base bro	eakdown voltage	V <sub>(BR)EBO</sub>	$I_E=1 \text{ mA}, I_C=0$	5			V
Forward current transfer	R	$\mathbf{h}_{ ext{FE}}$	V <sub>CE</sub> =2V; I <sub>C</sub> =1A	180		390	_
ratio <sup>1)</sup>	S	IIFE	VCE 2V, 1C 111	270	_	560	_
Collector-base co	utoff current	$I_{CBO}$	$V_{CB} = 30V, I_{E} = 0$	_		1	μА
Collector–emitter voltage <sup>1)</sup>	r saturation	V <sub>CE (sat)</sub>	I <sub>C</sub> =2A, I <sub>B</sub> =200mA		_	0.5	V
Transition freque	ency	$f_{T}$	I <sub>C</sub> =100mA , V <sub>CE</sub> =5V, f=100MHz	_	90	_	MHz
<sup>1)</sup> pulse method: t <sub>w</sub> :300μs, duty ratio≤2%.							

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Typical curve

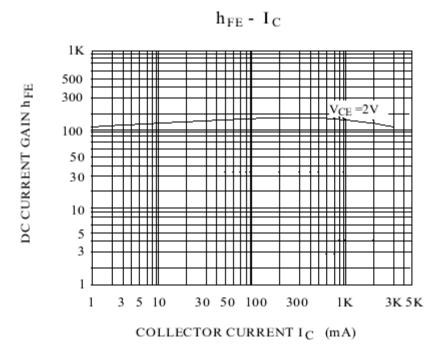
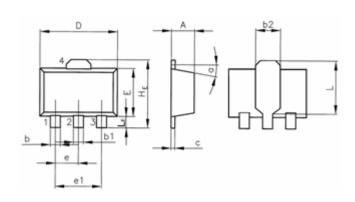


fig.1 Typical curve

### Outline dimensions



unit: mm

dimensions	SOT-89			
symbol	min	type	max	
A	1.4	_	1.6	
b	0.35	_	0.55	
b1	0.4	_	0.65	
b2	_	1.6	_	
С	0.35	_	0.45	
D	4.4	_	4.6	
Е	2.35	_	2.55	
e	_	1.5	_	
e1	_	3	_	
$H_{E}$	_	4.15	_	
L		2.7	_	
LE	_	1.0	_	
α	_	5°	_	

Fig.2 Outline dimensions

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